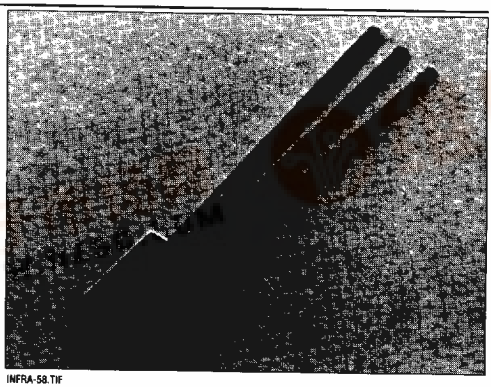
HLC1395

Reflective Sensor

FEATURES

- Side-looking plastic package
- Phototransistor output
- IR emitter and phototransistor detector in a single package
- Low profile for design flexibility
- Designed for short distance detection
- High sensitivity
- Unfocused for sensing diffused surfaces



INFRA-58.TIF

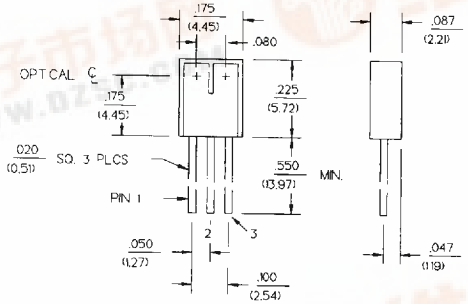
DESCRIPTION

The HLC1395 is a miniature infrared sensor designed to sense reflective objects at short distances. Both the GaAs IRED and the NPN phototransistor are mounted side-by-side in a single black plastic package with an integral barrier to minimize crosstalk. The sensor is configured with the IRED cathode and the phototransistor emitter connected to a common lead.

The housing consists of an opaque polysulfone outer shell with transfer-molded, IR-transmissive epoxy encapsulant. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

OUTLINE DIMENSIONS in inches (mm)

Tolerance 3 plc decimals ±0.010(0.25)
2 plc decimals ±0.030(0.76)



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ELECTRICAL CHARACTERISTIC (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	V_F			1.6	V	I_F=20 mA
Reverse Current	I_R			10	µA	V_R=3 V
DETECTOR						
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	30			V	I_C=100 µA
Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$	5.0			V	I_E=100 µA
Collector Dark Current	I_{CEO}			100	nA	V_{CE}=10 V, I_F=0
COUPLED CHARACTERISTICS						
On-State Collector Current	$I_{C(ON)}$				mA	V_{CE}=5 V
HLC1395-001		0.30				I_F=10 mA
HLC1395-002		0.60				(1)
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$			0.5	V	I_C=40 µA, I_F=10 mA (1)
Crosstalk (2)	I_{CX}			15	µA	V_{CE}=5 V, I_F=10 mA
Rise And Fall Time	t_r, t_f		15		µs	V_{CC}=5 V, I_C=0.3 mA, R_L=1000 Ω

Notes
1. Test surface is Eastman Kodak neutral white test card with 90% diffuse reflectance located 0.040 in. (1.0 mm) from the front surface of the device.
2. Crosstalk (Icx) is the collector current measured with current to emitter and no reflecting surface.

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range	-40°C to 85°C
Storage Temperature Range	-40°C to 85°C
Soldering Temperature (5 sec)	240°C
IR EMITTER	
Reverse Voltage	3 V
Continuous Forward Current	50 mA
Power Dissipation	100 mW (1)
DETECTOR	
Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5 V
Power Dissipation	100 mW (1)
Collector DC Current	30 mA

Notes
1. Derate linearly at 0.66 mW/°C above 25°C.

SCHEMATIC

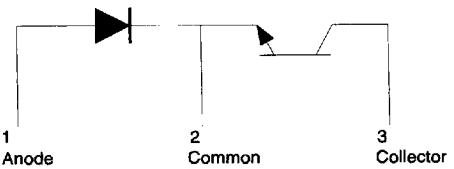

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Fig. 1 Normalized Light Current (I_L) vs Distance to Reflective Surface

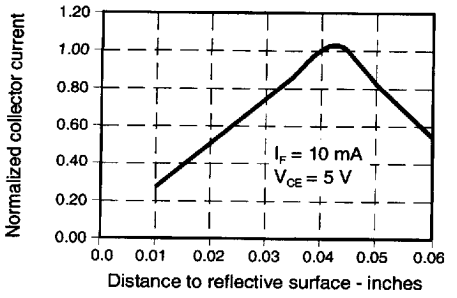


Fig. 2 Normalized Light Current (I_L) vs IRED Forward Current

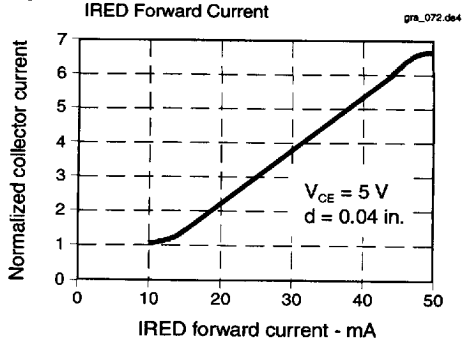


Fig. 3 IRED Forward Bias Characteristics

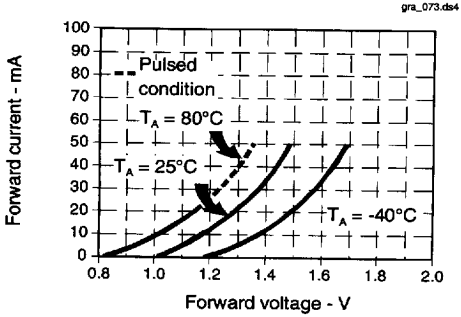


Fig. 4 Non-Saturated Switching Time vs Load Resistance

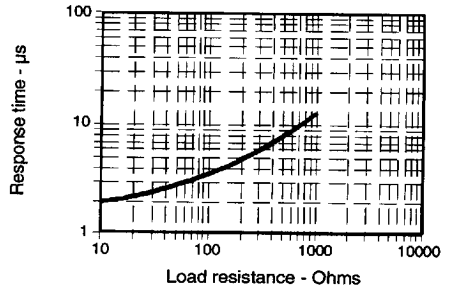


Fig. 5 Dark Current vs Temperature

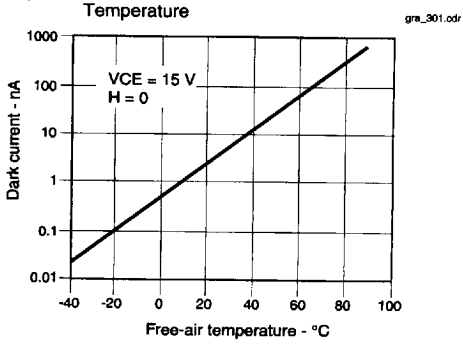
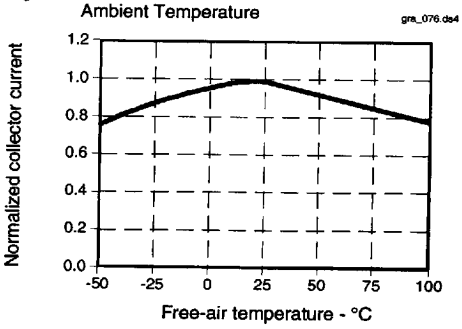


Fig. 6 Collector Current vs Ambient Temperature



All Performance Curves Show Typical Values